

Vishay Semiconductors

Ultra Fast Avalanche Sinterglass Diode



949539

MECHANICAL DATA

Case: SOD-57

Terminals: plated axial leads, solderable per MIL-STD-750,

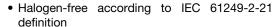
method 2026

Polarity: color band denotes cathode end

Mounting position: any **Weight:** approx. 369 mg

FEATURES

- Glass passivated junction
- Hermetically sealed axial-leaded glass envelope
- Low reverse current
- · Ultra fast soft recovery switching
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC







COMPLIANT HALOGEN FREE

APPLICATIONS

- Electronic ballast
- SMPS

PARTS TABLE		
PART	TYPE DIFFERENTIATION	PACKAGE
BYV27-600	V _R = 600 V; I _{FAV} = 2 A	SOD-57

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
Reverse voltage = repetitive peak reverse voltage	See electrical characteristics	BYV27-600	$V_R = V_{RRM}$	600	V	
Peak forward surge current	t _p = 10 ms, half sine wave		I _{FSM}	50	Α	
Average forward current	T _{amb} = 50 °C, I = 10 mm		I _{FAV}	2	Α	
Non repetitive reverse avalanche energy	Inductive load, I _{(BR)R} = 400 mA		E _R	10	mJ	
Junction and storage temperature range			$T_j = T_{stg}$	- 55 to + 175	°C	

MAXIMUM THERMAL RESISTANCE (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	TEST CONDITION SYMBOL VALUE		UNIT	
Junction ambient	Lead length I = 10 mm, T _L = constant	R_{thJA}	45	K/W	
	On PC board with spacing 25 mm	R_{thJA}	100	K/W	

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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 1 A		V_{F}	-	-	1.15	V
	I _F = 3 A		V_{F}	-	-	1.35	V
	I _F = 1 A, T _j = 175 °C		V_{F}	-	-	0.85	V
	I _F = 3 A, T _j = 175 °C		V_{F}	-	-	1.15	V
Reverse current	$V_R = V_{RRM}$		I _R	-	-	5	μA
	$V_R = V_{RRM}, T_j = 150 ^{\circ}C$		I _R	-	-	150	μA
Reverse breakdown voltage	I _R = 100 μA	BYV27-600	V _{(BR)R}	600	-	-	V
Reverse recovery time	I _F = 0.5 A, I _R = 1 A, i _R = 0.25 A		t _{rr}	-	-	40	ns
Forward recovery	I _F = 1 A		V_{FP}	-	3.4	-	V
Forward recovery time	I _F = 1 A		t _{fr}	-	250	-	ns

TYPICAL CHARACTERISTICS ($T_{amb} = 25$ °C, unless otherwise specified)

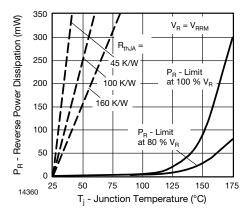


Fig. 1 - Max. Reverse Power Dissipation vs. Junction Temperature

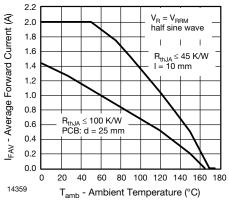


Fig. 3 - Max. Average Forward Current vs. Ambient Temperature

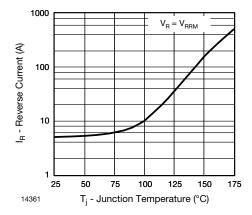


Fig. 2 - Max. Reverse Current vs. Junction Temperature

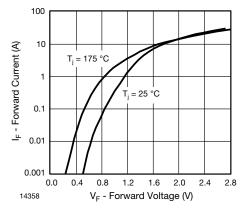


Fig. 4 - Max. Forward Current vs. Forward Voltage



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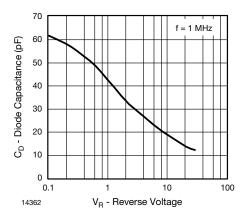
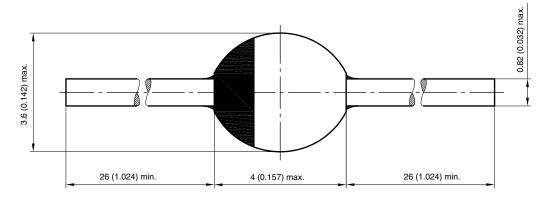


Fig. 5 - Typ. Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters (inches): SOD-57



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